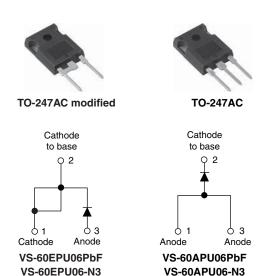


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Vishay Semiconductors

Ultrafast Soft Recovery Diode, 60 A FRED Pt®



PRODUCT SUMMARY									
Package	TO-247AC modified (2 pins), TO-247AC								
I _{F(AV)}	60 A								
V_{R}	600 V								
V _F at I _F	1.11 V								
t _{rr} typ.	See Recovery table								
T _J max.	175 °C								
Diode variation	Single die								

FEATURES

- Ultrafast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC®-JESD47
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912





ROHS
COMPLIANT
HALOGEN
FREE

BENEFITS

- Reduced RFI and EMI
- Higher frequency operation
- Reduced snubbing
- · Reduced parts count

DESCRIPTION / APPLICATIONS

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning systems.

The softness of the recovery eliminates the need for a snubber in most applications. These devices are ideally suited for HF welding, power converters and other applications where switching losses are not significant portion of the total losses.

ABSOLUTE MAXIMUM RATINGS											
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS							
Cathode to anode voltage	V_R		600	V							
Continuous forward current	I _{F(AV)}	T _C = 116 °C	60								
Single pulse forward current	I _{FSM}	T _C = 25 °C	600	Α							
Maximum repetitive forward current	I _{FRM}	Square wave, 20 kHz	120								
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C							

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS				
Breakdown voltage, blocking voltage	V _{BR} , V _R	Ι _R = 100 μΑ	600	-	-					
Forward voltage	V _F	I _F = 60 A	-	1.35	1.68	V				
		I _F = 60 A, T _J = 125 °C	-	1.20	1.42					
		I _F = 60 A, T _J = 175 °C	-	1.11	1.30					
Reverse leakage current		$V_R = V_R$ rated	-	-	50					
	I _R	T _J = 150 °C, V _R = V _R rated	-	-	500	μA				
Junction capacitance	C _T	V _R = 600 V	-	39	-	pF				



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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)										
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS				
		$I_F = 1 A, dI_F/dt = 20$	-	34	45					
Reverse recovery time	t _{rr}	T _J = 25 °C		-	81	-	ns			
		T _J = 125 °C		-	164	-				
Peak recovery current	I _{RRM}	T _J = 25 °C	I _F = 60 A dI _F /dt = 200 A/μs	-	7.4	-	А			
		T _J = 125 °C	$V_{\rm R} = 200 \text{ V}$	-	17.0	-				
Devenue verseure absence	Q _{rr}	T _J = 25 °C		=	300	-	nC			
Reverse recovery charge		T _J = 125 °C		=	1394	-				

THERMAL - MECHANICAL SPECIFICATIONS											
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS					
Thermal resistance, junction to case	R _{thJC}		-	-	0.63	K/W					
Thermal resistance, case to heatsink	R _{thCS}	Mounting surface, flat, smooth and greased	-	0.2	-	FX/VV					
Weight			-	5.5	-	g					
vveigni			-	0.2	-	oz.					
Mounting torque			1.2 (10)	-	2.4 (20)	N ⋅ m (lbf ⋅ in)					
Mandria a destina		Case style TO-247AC modified	60EPU06								
Marking device		Case style TO-247AC 60APU06			PU06						

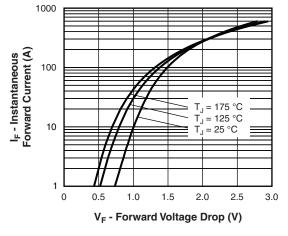


Fig. 1 - Typical Forward Voltage Drop Characteristics

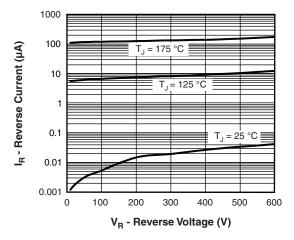


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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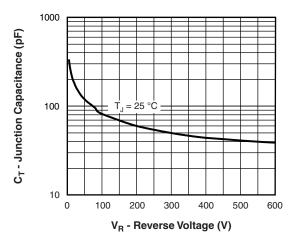


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

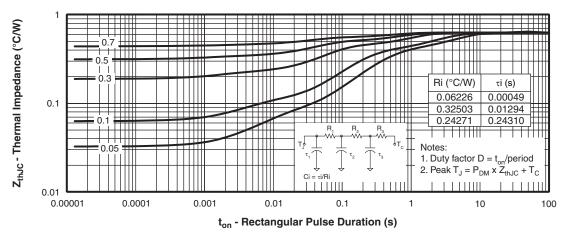


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

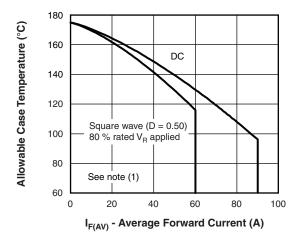


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

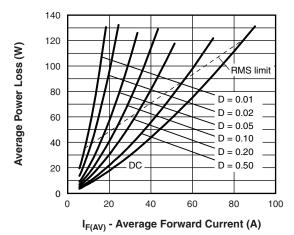


Fig. 6 - Forward Power Loss Characteristics

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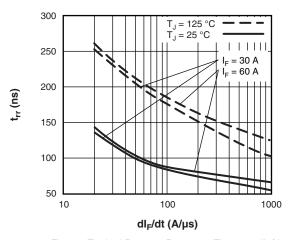


Fig. 7 - Typical Reverse Recovery Time vs. dI_{F}/dt

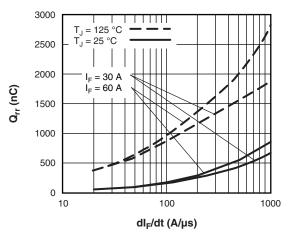


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

 $^{(1)}$ Formula used: T_C = T_J - (Pd + Pd_{REV}) x R_{th,JC}; Pd = Forward power loss = I_{F(AV)} x V_{FM} at (I_{F(AV)}/D) (see fig. 6); Pd_{REV} = Inverse power loss = V_{R1} x I_R (1 - D); I_R at V_{R1} = 80 % rated V_R

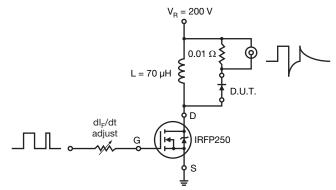
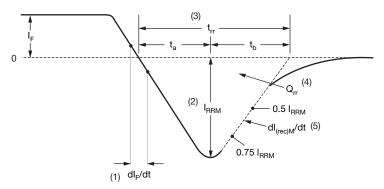


Fig. 9 - Reverse Recovery Parameter Test Circuit



- (1) dl_F/dt rate of change of current through zero crossing
- (2) I_{RRM} peak reverse recovery current
- (3) $\rm t_{rr}$ reverse recovery time measured from zero crossing point of negative going $\rm I_F$ to point where a line passing through 0.75 $\rm I_{RRM}$ and 0.50 $\rm I_{RRM}$ extrapolated to zero current.
- (4) \mathbf{Q}_{rr} area under curve defined by \mathbf{t}_{rr} and \mathbf{I}_{RRM}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

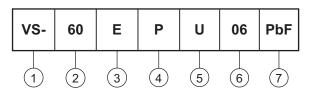
(5) dl_{(rec)M}/dt - peak rate of change of current during t_b portion of t_{rr}

Fig. 10 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating (60 = 60 A)

Circuit configuration:

• E = single diode

• A = single diode, 3 pins

4 - Package:

P = TO-247AC (modified)

5 - Type of silicon:

U = ultrafast recovery

6 - Voltage rating (06 = 600 V)

7 - Environmental digit:

PbF = lead (Pb)-free and RoHS-compliant

-N3 = halogen-free, RoHS-compliant and totally lead (Pb)-free

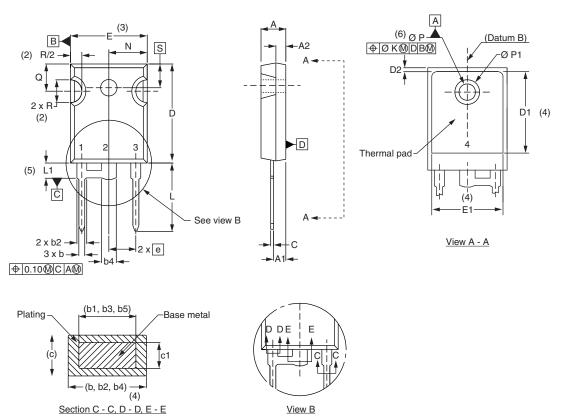
ORDERING INFORMATION (Example)										
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION							
VS-60EPU06PbF	25	500	Antistatic plastic tube							
VS-60EPU06-N3	25	500	Antistatic plastic tube							
VS-60APU06PbF	25	500	Antistatic plastic tube							
VS-60APU06-N3	25	500	Antistatic plastic tube							

LINKS TO RELATED DOCUMENTS								
Dimensions	TO-247AC modified	www.vishay.com/doc?95541						
	TO-247AC	www.vishay.com/doc?95542						
	TO-247AC modified PbF	www.vishay.com/doc?95255						
Part marking information	TO-247AC modified -N3	www.vishay.com/doc?95442						
Part marking information	TO-247ACPbF	www.vishay.com/doc?95226						
	TO-247AC-N3	www.vishay.com/doc?95007						

Vishay Semiconductors

TO-247 - 50 mils L/F modified

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	HES	NOTES		NOTES		CVMDOL	MILLIMETERS		INCHES		NOTES
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		
Α	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053			
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3		
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-			
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC			
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10			
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634			
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169			
b4	2.59	3.43	0.102	0.135			N	7.62	BSC	0	.3			
b5	2.59	3.38	0.102	0.133			ØΡ	3.56	3.66	0.14	0.144			
С	0.38	0.89	0.015	0.035			Ø P1	-	7.39	-	0.291			
c1	0.38	0.84	0.015	0.033			Q	5.31	5.69	0.209	0.224			
D	19.71	20.70	0.776	0.815	3		R	4.52	5.49	0.178	0.216			
D1	13.08	-	0.515	=.	4		S	5.51	BSC	0.217	BSC			

Notes

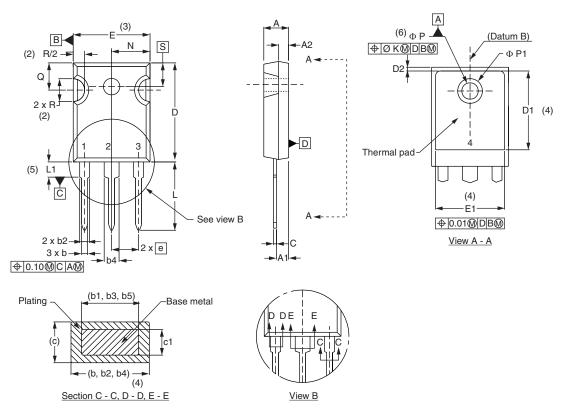
- (1) Dimensioning and tolerance per ASME Y14.5M-1994
- (2) Contour of slot optional
- (3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- (5) Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- (7) Outline conforms to JEDEC® outline TO-247 with exception of dimension c and Q



Vishay Semiconductors

TO-247 - 50 mils L/F

DIMENSIONS in millimeters and inches



CVMDOL	MILLIM	MILLIMETERS		RS INCHES		NOTES	CVMDOL	MILLIMETERS		INCHES		NOTEO
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
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Revision: 02-Oct-12 Document Number: 91000

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ACGRB207-HF CLH03(TE16L,Q) ACGRC307-HF ACEFC304-HF NTE6356 NTE6359 NTE6002 NTE6023 NTE6039 NTE6077

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